<u>SENSITRON</u> SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 5147, Rev A.1

HERMETIC ULTRAFAST RECTIFIER

DESCRIPTION: A 200-VOLT, 80 AMP, 50 NANOSECOND RECTIFIER IN A HERMETIC SMD-1 PACKAGE.

FEATURES:

- Soft Reverse Recovery to minimize snubbers / EMI issues
- Low profile ceramic package for reduced inductance
- Low forward drop
- Available with JANTX, JANTXV, JANS equivalent screening

MAXIMUM RATINGS

ALL RATINGS ARE AT $T_A = 25$ C) UNLESS OTHERWISE SPECIFIED

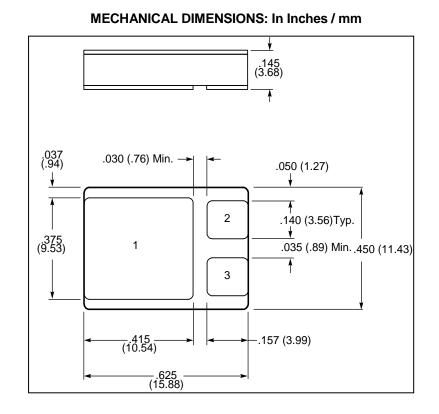
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE (PER LEG)	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT ($T_c = 100$ °C)	lo	80	Amps
PEAK SINGLE CYCLE SURGE CURRENT $t_p = 8.3$ msec	I _{FSM}	250	Amps
MAXIMUM THERMAL RESISTANCE	R _{0JC}	0.8	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE		-65 to +175	°C

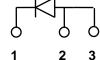
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP			
$I_f = 5 \text{ Amps}, T_C = 25^{\circ}C$	V _{f1}	0.78	V
$I_f = 25 \text{ Amps}, T_C = 25^{\circ}C$	V _{f2}	0.90	
$I_f = 50 \text{ Amps}, T_C = 25^{\circ}C$	V _{f3}	1.05	
$I_f = 80 \text{ Amps}, T_C = 25^{\circ}C$	V _{f4}	1.15	
I _f = 50 Amps, T _C = -55°C	V _{f5}	1.15	
$I_{f} = 50 \text{ Amps}, T_{C} = 100^{\circ}\text{C}$	V _{f6}	0.90	
MAXIMUM REVERSE CURRENT I _r @ 200V, $T_C = 25^{\circ}C$	l _r	50	μA
MAXIMUM REVERSE CURRENT I _r @ 200V, $T_c = 100^{\circ}C$	l _r	8	mA
MAXIMUM REVERSE RECOVERY TIME	t _{RR}	60	ns
$I_F = 9.9A, dI_F/dt = 200 A/\mu s, V_R = 30V, T_C = 25^{\circ}C$			
MAXIMUM REVERSE RECOVERY Current	I _{RM}	7	А
$I_F = 9.9A, dI_F/dt = 200 A/\mu s, V_R = 30V, T_C = 25^{\circ}C$			

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SMD-1

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE

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